Amplifier Transistors

NPN Silicon

Features

• Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Collector - Emitter Voltage	BC546 BC547 BC548	V _{CEO}	65 45 30	Vdc
Collector - Base Voltage	BC546 BC547 BC548	V _{CBO}	80 50 30	Vdc
Emitter - Base Voltage		V _{EBO}	6.0	Vdc
Collector Current - Continuous		I _C	100	mAdc
Total Device Dissipation @ T _A = 2 Derate above 25°C	25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 2 Derate above 25°C	25°C	P _D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range		T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

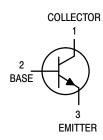
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

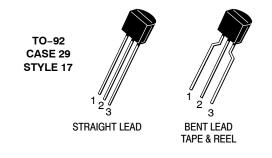
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



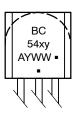
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



x = 6, 7, or 8y = A, B or C

A = Assembly Location

Y = Year WW = Work Week • = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS			I.	I.		u .
Collector – Emitter Breakdown Voltage $(I_C = 1.0 \text{ mA}, I_B = 0)$	BC546 BC547 BC548	V _(BR) CEO	65 45 30	- - -	- - -	V
Collector – Base Breakdown Voltage (I_C = 100 μ Adc)	BC546 BC547 BC548	V _{(BR)CBO}	80 50 30	- - -	- - -	V
Emitter – Base Breakdown Voltage (I_E = 10 μ A, I_C = 0)	BC546 BC547 BC548	V _{(BR)EBO}	6.0 6.0 6.0	- - -	- - -	V
Collector Cutoff Current	BC546 BC547 BC548 6/547/548	I _{CES}	- - - -	0.2 0.2 0.2 -	15 15 15 4.0	nA μA
ON CHARACTERISTICS						
DC Current Gain (I _C = 10 μ A, V _{CE} = 5.0 V) BC546B/54	BC547A 17B/548B BC548C	h _{FE}	- - -	90 150 270	- - -	-
$(I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$ BC546B/54 BC547C	BC546 BC547 BC548 BC547A 47B/548B /BC548C		110 110 110 110 200 420	- - 180 290 520	450 800 800 220 450 800	
$(I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V})$ BC546B/54	17A/548A 17B/548B BC548C		- - -	120 180 300	- - -	
Collector – Emitter Saturation Voltage (I_C = 10 mA, I_B = 0.5 mA) (I_C = 100 mA, I_B = 5.0 mA) (I_C = 10 mA, I_B = See Note 1)		V _{CE(sat)}	- - -	0.09 0.2 0.3	0.25 0.6 0.6	V
Base – Emitter Saturation Voltage $(I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA})$		V _{BE(sat)}	-	0.7	-	V
Base – Emitter On Voltage (I_C = 2.0 mA, V_{CE} = 5.0 V) (I_C = 10 mA, V_{CE} = 5.0 V)		V _{BE(on)}	0.55 -	- -	0.7 0.77	V
SMALL-SIGNAL CHARACTERISTICS						
Current - Gain - Bandwidth Product (I_C = 10 mA, V_{CE} = 5.0 V, f = 100 MHz)	BC546 BC547 BC548	f⊤	150 150 150	300 300 300	- - -	MHz
Output Capacitance ($V_{CB} = 10 \text{ V}, I_C = 0, f = 1.0 \text{ MHz}$)		C_{obo}	-	1.7	4.5	pF
Input Capacitance (V _{EB} = 0.5 V, I _C = 0, f = 1.0 MHz)		C _{ibo}	-	10	-	pF
BC546B/54	BC546 C547/548 BC547A 47B/548B 47C/548C	h _{fe}	125 125 125 125 240 450	- 220 330 600	500 900 260 500 900	-
Noise Figure (I _C = 0.2 mA, V _{CE} = 5.0 V, R _S = 2 k Ω , f = 1.0 kHz, Δ f =	200 Hz) BC546 BC547 BC548	NF	- - -	2.0 2.0 2.0	10 10 10	dB

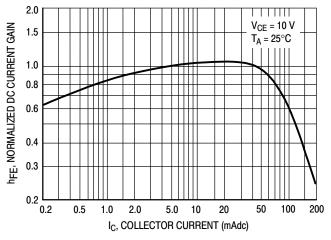
^{1.} I_B is value for which I_C = 11 mA at V_{CE} = 1.0 V.

BC547/BC548

1.0

0.9

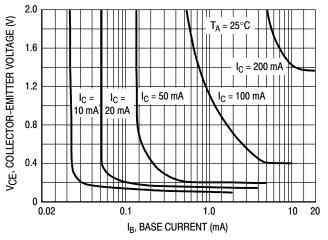
 $T_A = 25^{\circ}C$



8.0 $V_{BE(sat)} @ I_C/I_B = 10$ 0.7 V, VOLTAGE (VOLTS) V_{BE(on)} @ V_{CE} = 10 V 0.6 0.5 0.4 0.3 0.2 $V_{CE(sat)} @ I_C/I_B = 10$ 0.1 0.2 0.3 0.5 0.7 1.0 2.0 3.0 5.0 7.0 10 20 30 50 70 100 0.1 IC, COLLECTOR CURRENT (mAdc)

Figure 1. Normalized DC Current Gain

Figure 2. "Saturation" and "On" Voltages



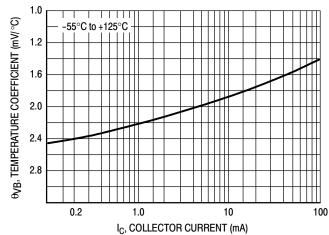
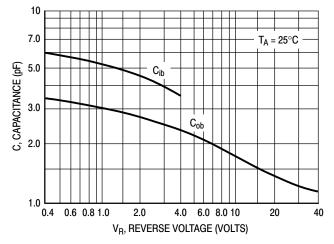


Figure 3. Collector Saturation Region

Figure 4. Base-Emitter Temperature Coefficient



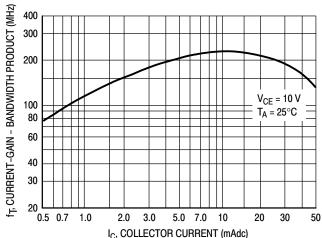


Figure 5. Capacitances

Figure 6. Current-Gain - Bandwidth Product

BC546

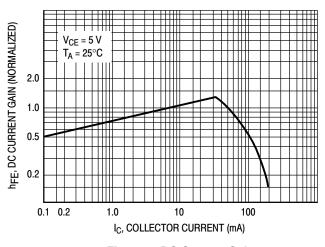


Figure 7. DC Current Gain

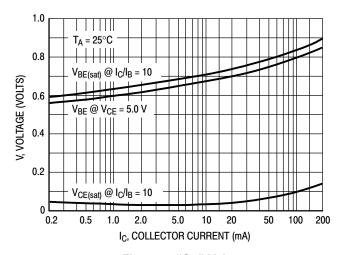


Figure 8. "On" Voltage

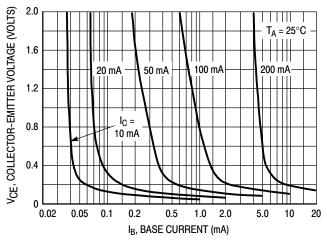


Figure 9. Collector Saturation Region

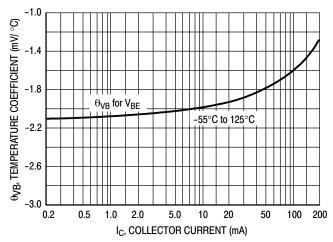


Figure 10. Base-Emitter Temperature Coefficient

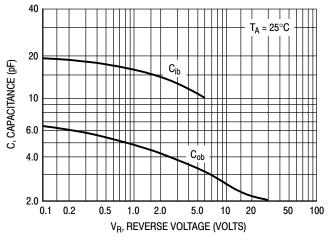


Figure 11. Capacitance

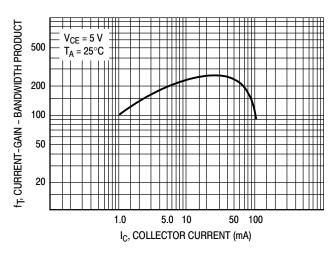
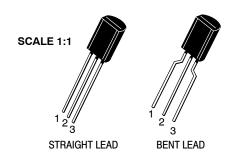


Figure 12. Current-Gain - Bandwidth Product

ORDERING INFORMATION

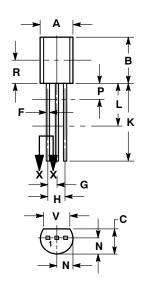
Device	Package	Shipping [†]
BC546B	TO-92	5000 Units / Bulk
BC546BG	TO-92 (Pb-Free)	5000 Units / Bulk
BC546BRL1	TO-92	2000 / Tape & Reel
BC546BRL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
BC546BZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC547ARL	TO-92	2000 / Tape & Reel
BC547ARLG	TO-92 (Pb-Free)	2000 / Tape & Reel
BC547AZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC547BG	TO-92 (Pb-Free)	5000 Units / Bulk
BC547BRL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
BC547BZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC547CG	TO-92 (Pb-Free)	5000 Units / Bulk
BC547CZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC548BG	TO-92 (Pb-Free)	5000 Units / Bulk
BC548BRL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
BC548BZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC548CG	TO-92 (Pb-Free)	5000 Units / Bulk
BC548CZL1G	TO-92 (Pb-Free)	2000 / Ammo Box

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



TO-92 (TO-226) 1 WATT CASE 29-10 **ISSUE A**

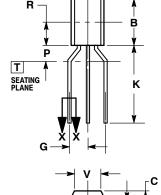
DATE 08 MAY 2012



STRAIGHT LEAD



BENT LEAD





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- 714.5M, 1994.
 CONTROLLING DIMENSION: INCHES.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS
 UNCONTROLLED.
- UNIONI HOLLEU, DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L DIMENSIONS D AND J APPLY BETWEEN DI-MENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.135		3.43	
٧	0.135		3.43	

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME
- CONTROLLING DIMENSION: INCHES.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L. DIMENSIONS D AND J APPLY BETWEEN DIMENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.44	5.21	
В	0.290	0.310	7.37	7.87	
С	0.125	0.165	3.18	4.19	
D	0.018	0.021	0.46	0.53	
G	0.094	0.102	2.40	2.80	
J	0.018	0.024	0.46	0.61	
K	0.500		12.70		
N	0.080	0.105	2.04	2.66	
P		0.100		2.54	
R	0.135		3.43		
٧	0.135		3.43		

STYLES ON PAGE 2

DOCUMENT NUMBER:	98AON52857E	Electronic versions are uncontrolled except when accessed directly from the Document Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
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ISSUE A

DATE 08 MAY 2012

STYLE 1: PIN 1. 2. 3.	EMITTER BASE COLLECTOR	STYLE 2: PIN 1. 2. 3.	BASE EMITTER COLLECTOR	STYLE 3: PIN 1. 2. 3.	ANODE ANODE CATHODE	STYLE 4: PIN 1. 2. 3.	CATHODE CATHODE ANODE	STYLE 5: PIN 1. 2. 3.	DRAIN SOURCE GATE
	GATE SOURCE & SUBSTRATE DRAIN	STYLE 7: PIN 1. 2. 3.	SOURCE DRAIN GATE	STYLE 8: PIN 1. 2. 3.	DRAIN GATE SOURCE & SUBSTRATE	STYLE 9: PIN 1. 2. 3.	BASE 1 EMITTER BASE 2	STYLE 10: PIN 1. 2. 3.	CATHODE GATE ANODE
2.	ANODE CATHODE & ANODE CATHODE	STYLE 12: PIN 1. 2. 3.	MAIN TERMINAL 1 GATE MAIN TERMINAL 2	STYLE 13: PIN 1. 2. 3.	ANODE 1 GATE CATHODE 2	STYLE 14: PIN 1. 2. 3.	EMITTER COLLECTOR BASE	STYLE 15: PIN 1. 2. 3.	ANODE 1 CATHODE ANODE 2
PIN 1. 2.	ANODE	PIN 1.	COLLECTOR BASE EMITTER	STYLE 18: PIN 1. 2. 3.	ANODE	STYLE 19: PIN 1. 2. 3.	GATE ANODE CATHODE	2.	NOT CONNECTED CATHODE ANODE
PINI 1	COLLECTOR EMITTER BASE	PIN 1.	SOURCE	PIN 1.	GATE	PIN 1. 2.	EMITTER	PIN 1. 2.	MT 1
	V _{CC} GROUND 2 OUTPUT	STYLE 27: PIN 1. 2. 3.	MT SUBSTRATE MT	2.	CATHODE ANODE GATE	2.	NOT CONNECTED ANODE CATHODE	2.	DRAIN GATE SOURCE
PIN 1. 2.	GATE DRAIN SOURCE	PIN 1.	BASE	PIN 1. 2.	RETURN INPUT OUTPUT	PIN 1. 2.	INPUT GROUND LOGIC		

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